# MOS INTEGRATED CIRCUIT $\mu$ PD16805

# MONOLITHIC H BRIDGE DRIVER CIRCUIT

# DESCRIPTION

NEC

The  $\mu$ PD16805 is a monolithic H bridge driver IC which uses low-ON resistance power MOS FETs in its driver stage. This driver has a forward, reverse, and brake functions and is ideal for the driver circuit of motors for camera that advance or rewind the film, and for auto focusing or zooming.

This IC supports a drive current of up to 1.0 A (DC).

# FEATURES

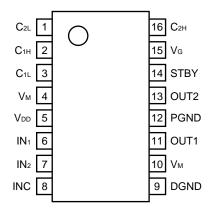
- High drive current
- $\label{eq:Idr} \begin{array}{l} \mbox{Idr}=4.2\mbox{ A MAX. at PW} \leq 200\mbox{ ms (single pulse)} \\ \mbox{Idr}=1.0\mbox{ A (DC)} \end{array}$
- Low-ON resistance (sum of ON resistances of top and bottom MOS FET)

Ron = 0.4  $\Omega$  TYP. at IDR = 1.0 A

- Standby function that turns OFF charge pump circuit
- Compact surface mount package
  16-pin plastic SOP (300 mil)

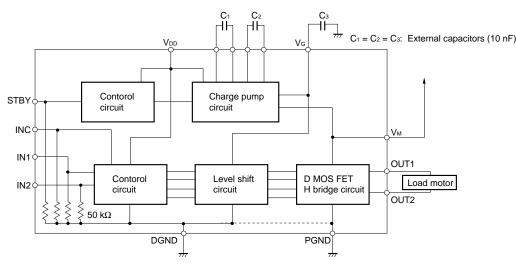
# ORDERING INFORMATION

# PIN CONFIGURATION (Top View)



Part Number	Package
μPD16805GS	16-pin plastic SOP (300 mil)

# **BLOCK DIAGRAM**



The information in this document is subject to change without notice.

# ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Conditions	Rating	Unit
Supply voltage	Vdd		-0.5 to +6.5/+8.0 <sup>Note</sup>	V
	Vм		-0.5 to +6.5/+8.0 <sup>Note</sup>	
V <sub>G</sub> pin applied voltage	Vg		15	V
Input voltage	Vin		-0.5 to V <sub>DD</sub> + 0.5	V
H bridge drive current	IDR1	DC	1.0	А
	Idr2	$PW \le 200 \text{ ms} \text{ (single pulse)}$	4.2	А
Power consumption	Рт	T <sub>A</sub> = 25 °C	1.0	W
Operating temperature range	TA		-30 to +60	°C
Operating junction temperature	TJ (MAX)		150	°C
Storage temperature range	Tstg		-55 to +150	°C

Note  $\,V_{DD}$  when the charge pump is used/V\_{DD} and V\_M when V\_G is supplied from an external source

# **RECOMMENDED OPERATING CONDITIONS**

Parameter	Symbol	Conditions	Ratings			Unit
Farameter	Symbol	Conditions	MIN.	TYP.	MAX.	Onit
Supply voltage	V <sub>DD</sub> During normal operation		3.0		6.0/7.5 <sup>Note 2</sup>	V
		All input pins are low	2.5			
	Vм		0.5		7.5	V
Charge pump capacitance	C <sub>1</sub> to C <sub>3</sub>			10		nF
V <sub>G</sub> pin applied voltage <sup>Note 1</sup>	Vg		11		14	V
Operating temperature	TA	Ambient temperature	-30		60	°C

Notes 1. When a voltage is applied from an external source to the  $\ensuremath{\mathsf{V}}\xspace{\mathsf{g}}$  pin

2. When the charge pump is used/when  $\ensuremath{\mathsf{V}}\xspace{\mathsf{G}}$  is supplied from an external source

# ELECTRICAL SPECIFICATIONS (Unless otherwise specified, $T_A = 25$ °C, $V_{DD} =$ recommended operating condition, $V_M = 0.5$ to 7.5 V)

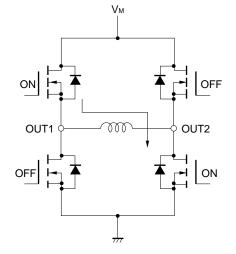
Descention	Symbol	Que ell'ittere e	Ratings			
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
V <sub>DD</sub> pin current	Idd1	V <sub>DD</sub> = 5 V, T <sub>A</sub> = recommended conditions Control pins at high level		0.6	2.0	mA
	Idd2	V <sub>DD</sub> = 5 V, T <sub>A</sub> = recommended conditions Control pins at low level		0.3	10	μA
V <sub>M</sub> pin current	Ім1	Control pins at low level, T <sub>A</sub> = recommended conditions		0.1	10	μΑ
	Ім2	Control pins at low level			1.0	μΑ
H bridge ON resistance <sup>Note</sup>	Ron	Idr = 1.0 A, Vdd = Vm = 5 V		0.4	0.6	Ω
Control pin high-level input voltage	Vін	T <sub>A</sub> = recommended condition	$V_{\text{DD}} \times 0.6$			V
Control pin low-level input voltage	VIL	T <sub>A</sub> = recommended condition			$V_{\text{DD}} \times 0.2$	V
Charge pump circuit turn-ON time	tong	$V_{DD} = V_M = 5 V,$		0.5	1.0	ms
H bridge output circuit turn-ON time	tолн	T <sub>A</sub> = recommended conditions			10	μs
H bridge output circuit turn-OFF time	toffh	$C_1 = C_2 = C_3 = 10 \text{ nF}$ Idr = 1.0 A			5.0	μs
Control pin input pull-down resistor	RIND		35	50	65	kΩ
		T <sub>A</sub> = recommended condition	25		75	kΩ

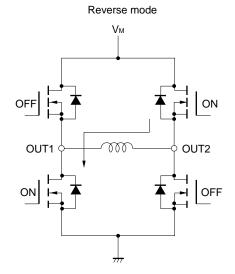
Note Sum of ON resistances of top and bottom MOS FETs

# FUNCTION TABLE

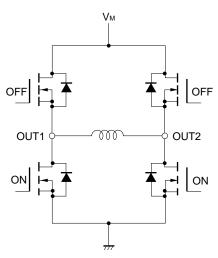
Input Signal			Function			
IN1	IN2	INC	STB	Function		
н	L	Н	н	Forward mode		
L	Н	Н	н	Reverse mode		
Н	Н	Н	Н	Brake mode		
L	L	Н	н	Stop mode		
×	×	L	н	Stop mode		
×	×	×	L	Standby mode		

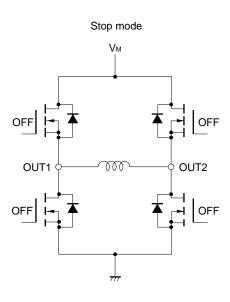
Forward mode

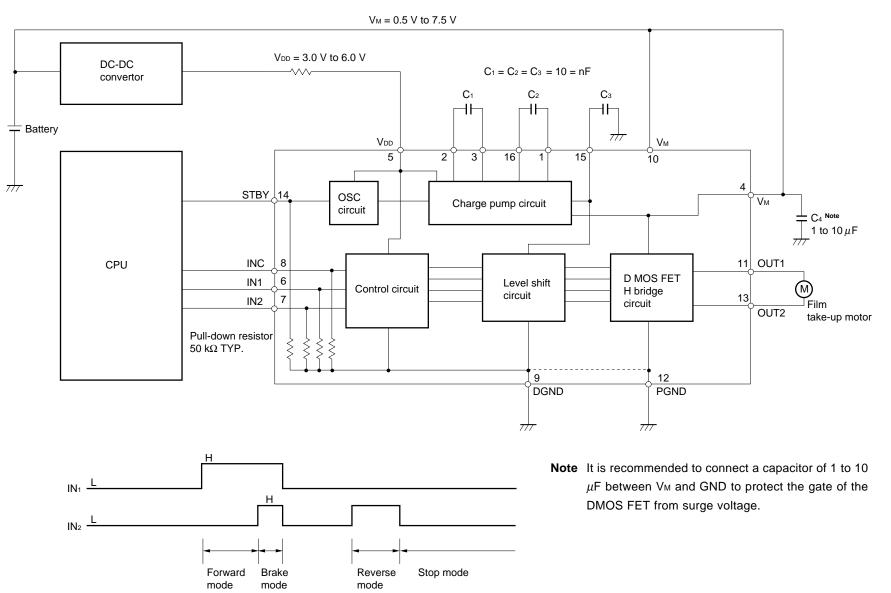




Brake mode

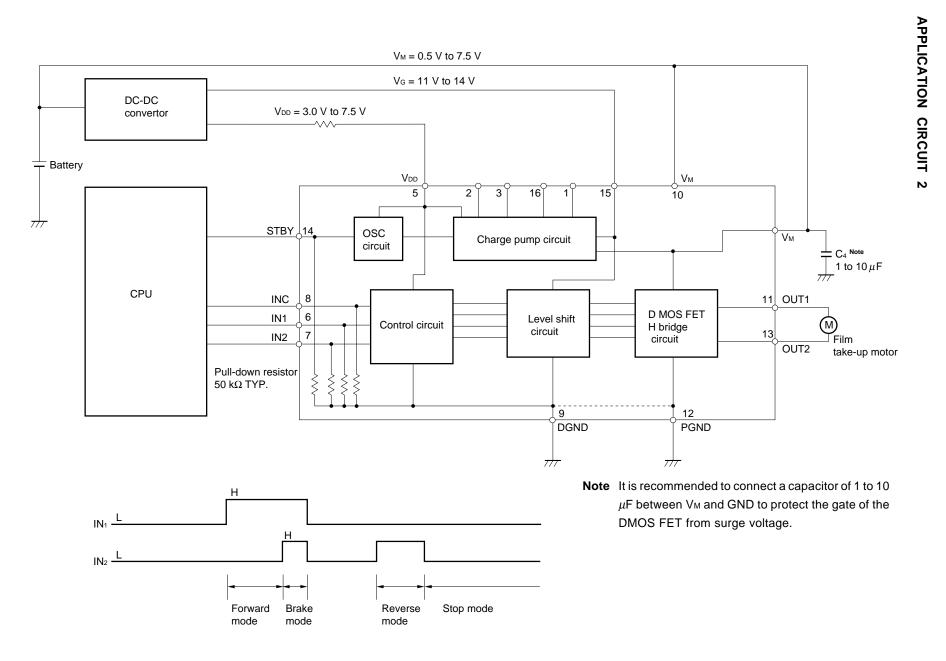




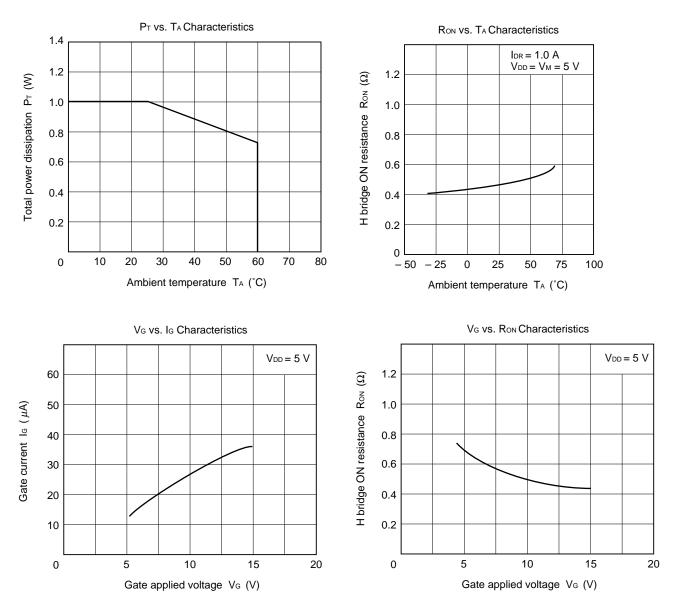


# APPLICATION CIRCUIT 1

μ**PD16805** 

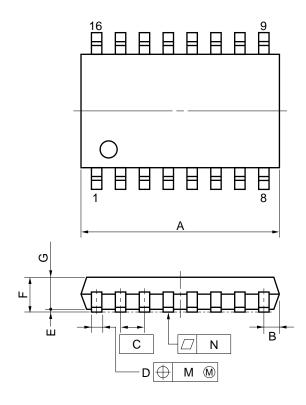


TYPICAL CHARACTERISTICS (TA = 25  $^{\circ}$ C)

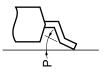


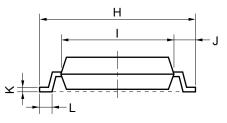
# PACKAGE DIMENSION

# 16 PIN PLASTIC SOP (300 mil)



detail of lead end





### NOTE

Each lead centerline is located within 0.12 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS	INCHES
А	10.46 MAX.	0.412 MAX.
В	0.78 MAX.	0.031 MAX.
С	1.27 (T.P.)	0.050 (T.P.)
D	$0.40^{+0.10}_{-0.05}$	$0.016\substack{+0.004\\-0.003}$
E	0.1±0.1	0.004±0.004
F	1.8 MAX.	0.071 MAX.
G	1.55	0.061
Н	7.7±0.3	0.303±0.012
I	5.6	0.220
J	1.1	0.043
к	$0.20^{+0.10}_{-0.05}$	$0.008^{+0.004}_{-0.002}$
L	0.6±0.2	$0.024^{+0.008}_{-0.009}$
М	0.12	0.005
Ν	0.10	0.004
Ρ	3° <sup>+7°</sup> -3°	3° <sup>+7°</sup> -3°
		216GM-50-300B-/

P16GM-50-300B-4

# **RECOMMENDED SOLDERING CONDITIONS**

It is recommended to solder this product under the conditions described below. For soldering methods and conditions other than those listed below, consult NEC.

## Surface mount type

For the details of the recommended soldering conditions of this type, refer to **Semiconductor Device Mounting Technology Manual (C10535E)**.

# μ**PD16805GS**

Soldering Method	Soldering Conditions	Symbol of Recommended Soldering
Infrared reflow	Peak package temperature: 235 °C, Time: 30 seconds MAX. (210 °C MIN.), Number of times: 2 MAX.	IR35-00-2
VPS	Peak package temperature: 215 °C, Time: 40 seconds MAX. (200 °C MIN.), Number of times: 2 MAX.	VP15-00-2

Note The number of storage days at 25  $^\circ\text{C},\,65\%$  RH after the dry pack has been opened

[MEMO]

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Anti-radioactive design is not implemented in this product.